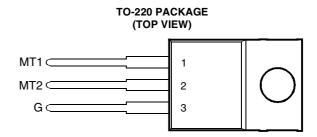
BOURNS®

- Sensitive Gate Triacs
- 4 A RMS
- Glass Passivated Wafer
- 400 V to 700 V Off-State Voltage
- Max I_{GT} of 5 mA (Quadrants 1 3)



Pin 2 is in electrical contact with the mounting base.

MDC2ACA

absolute maximum ratings over operating case temperature (unless otherwise noted)

| RATING | SYMBOL | VALUE | UNIT | |
|---|-----------------|------------------|-------------|----|
| | TIC206D | | 400 | |
| Repetitive peak off-state voltage (see Note 1) | TIC206M | V _{DRM} | 600 | V |
| | TIC206S | | 700 | |
| Full-cycle RMS on-state current at (or below) 85°C case temperature (see Note | T(RMS) | 4 | Α | |
| Peak on-state surge current full-sine-wave at (or below) 25°C case temperature (see Note 3) | | | 25 | Α |
| Peak gate current | I _{GM} | ±0.2 | Α | |
| Peak gate power dissipation at (or below) 85°C case temperature (pulse width ≤ | P _{GM} | 1.3 | W | |
| Average gate power dissipation at (or below) 85°C case temperature (see Note 4) | | | 0.3 | W |
| Operating case temperature range | | | -40 to +110 | °C |
| Storage temperature range | | | -40 to +125 | °C |
| Lead temperature 1.6 mm from case for 10 seconds | T _L | 230 | °C | |

- NOTES: 1. These values apply bidirectionally for any value of resistance between the gate and Main Terminal 1.
 - 2. This value applies for 50-Hz full-sine-wave operation with resistive load. Above 85°C derate linearly to 110°C case temperature at the rate of 160 mA/°C.
 - 3. This value applies for one 50-Hz full-sine-wave when the device is operating at (or below) the rated value of on-state current. Surge may be repeated after the device has returned to original thermal equilibrium. During the surge, gate control may be lost.
 - 4. This value applies for a maximum averaging time of 20 ms.

electrical characteristics at 25°C case temperature (unless otherwise noted)

| PARAMETER TEST CONDITIONS | | | MIN | TYP | MAX | UNIT | | |
|---------------------------|-----------------------------------|---|--------------------|---------------------------|-----|------|----|------|
| I _{DRM} | Repetitive peak off-state current | $V_D = \text{rated } V_{DRM}$ | I _G = 0 | T _C = 110°C | | | ±1 | mA |
| I _{GT} | | $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ | $R_L = 10 \Omega$ | t _{p(g)} > 20 μs | | 0.9 | 5 | |
| | Gate trigger | $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ | $R_L = 10 \Omega$ | $t_{p(g)} > 20 \mu s$ | | -2.2 | -5 | mA |
| | current $V_{\text{supply}} = -1$ | $V_{\text{supply}} = -12 \text{ V}\dagger$ | $R_L = 10 \Omega$ | $t_{p(g)} > 20 \mu s$ | | -1.8 | -5 | IIIA |
| | | $V_{\text{supply}} = -12 \text{ V}\dagger$ | $R_L = 10 \Omega$ | $t_{p(g)} > 20 \ \mu s$ | | 2.4 | 10 | |

† All voltages are with respect to Main Terminal 1.

PRODUCT INFORMATION



electrical characteristics at 25°C case temperature (unless otherwise noted) (continued)

| PARAMETER TEST CONDITIONS | | | MIN | TYP | MAX | UNIT | | |
|---------------------------|--|--|--|--|-----|-------------|-----------|------|
| | Gate trigger | $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ | $R_L = 10 \Omega$ $R_L = 10 \Omega$ | t _{p(g)} > 20 μs t _{p(g)} > 20 μs | | 0.7 -0.7 | 2 -2 | |
| V _{GT} | voltage | V _{supply} = -12 V† | $R_L = 10 \Omega$ | $t_{p(g)} > 20 \mu s$ | | -0.7 | -2 | V |
| | | $V_{\text{supply}} = -12 \text{ V}\dagger$ | $R_L = 10 \Omega$ | $t_{p(g)} > 20 \mu s$ | | 0.7 | 2 | |
| V_{T} | On-state voltage | $I_T = \pm 4.2 \text{ A}$ | $I_G = 50 \text{ mA}$ | (see Note 5) | | ±1.4 | ±2.2 | V |
| I _H | Holding current | $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ | $I_G = 0$ | Init' $I_{TM} = 100 \text{ mA}$ | | 1.5 | 15 | mA |
| | | $V_{\text{supply}} = -12 \text{ V}^{\dagger}$ | $I_G = 0$ | Init' $I_{TM} = -100 \text{ mA}$ | | -1.3 | -15 | ША |
| IL | Latching current | $V_{\text{supply}} = +12 \text{ V}^{\dagger}$ $V_{\text{supply}} = -12 \text{ V}^{\dagger}$ | (see Note 6) | | | | 30 -30 | mA |
| dv/dt | Critical rate of rise of off-state voltage | $V_{DRM} = Rated V_{DRM}$ | I _G = 0 | T _C = 110°C | | ±20 | | V/µs |
| dv/dt _(c) | Critical rise of commutation voltage | $V_{DRM} = Rated V_{DRM}$ | I _{TRM} = ±4.2 A | T _C = 85°C | ±1 | ±3 | | V/µs |

[†] All voltages are with respect to Main Terminal 1.

NOTES: 5. This parameter must be measured using pulse techniques, $t_p = \le 1$ ms, duty cycle ≤ 2 %. Voltage-sensing contacts separate from the current carrying contacts are located within 3.2 mm from the device body.

6. The triacs are triggered by a 15-V (open circuit amplitude) pulse supplied by a generator with the following characteristics: $R_G = 100 \ \Omega$, $t_{p(g)} = 20 \ \mu s$, $t_r = \le 15 \ ns$, $f = 1 \ kHz$.

thermal characteristics

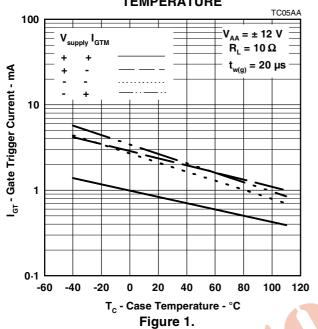
| PARAMETER | | | | MAX | UNIT |
|-----------------|---|--|--|------|------|
| $R_{\theta JC}$ | Junction to case thermal resistance | | | 7.8 | °C/W |
| $R_{\theta JA}$ | Junction to free air thermal resistance | | | 62.5 | °C/W |
| | | | | | |

BOURNS®

TYPICAL CHARACTERISTICS

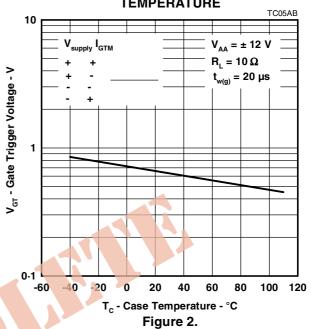
GATE TRIGGER CURRENT vs

TEMPERATURE

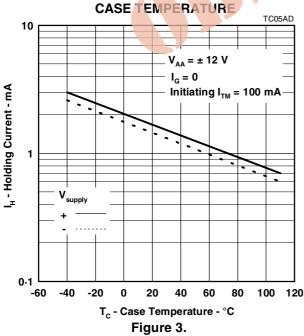


GATE TRIGGER VOLTAGE

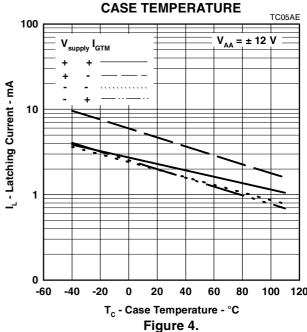
TEMPERATURE



HOLDING CURRENT



LATCHING CURRENT vs



PRODUCT INFORMATION

DECEMBER 1971 - REVISED SEPTEMBER 2002 Specifications are subject to change without notice.